

Amendment to the Specification

On page 1, after the Title, please insert the following new paragraph:

CROSS REFERENCE TO RELATED APPLICATION

This patent application is a Division of U.S. Patent Application Serial No. 10/280,757, filed October 21, 2002, entitled "A $6F^2$ DRAM Array, A DRAM Array Formed On A Semiconductive Substrate, A Method Of Forming Memory Cells In A $6F^2$ DRAM Array And A Method Of Isolating A Single Row Of Memory Cells In A $6F^2$ DRAM Array", naming Luan Tran as inventor, which in turn was a Division of U.S. Patent Application Serial No. 09/810,933, filed March 16, 2001, now U.S. Patent No. 6,545,904, the disclosure of which is hereby incorporated herein by reference.